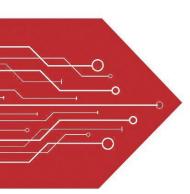
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data speet

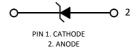
Semiconductor

Compiance

Specification Features:

- Ultra Low Capacitance 0.5 pF
- Low Clamping Voltage
- Small Body Outline Dimensions: 0.039" x 0.024" (1.00 mm x 0.60 mm)
- Low Body Height: 0.016" (0.4 mm)
- Stand-off Voltage: 5 V
- Low Leakage
- Response Time is Typically < 1.0 ns
- IEC61000-4-2 Level 4 ESD Protection
- This is a Pb-Free Device
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.





SOD-923

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted, VF = 1.0 V Max. @ IF = 10 mA for all types)

50.	V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	Ι _Τ	С	(pF)	Vc (V) @ Ipp = 1 A (Note 3)	Vc
P/N	Max	Max	Min	mA	Тур	Max	Max	Per IEC61000-4-2 (Note 4)
ESD9X5.0ST5G-MS	5.0	1.0	5.4	1.0	15	15	9.8	Figures 1 and 2 See Below

- 2. VBR is measured with a pulse test current IT at an ambient temperature of 25°C.
- Surge cuprrent waveform perFigure 5.
- 4. For test rocedure see Fi ures 3 and 4.

ELECTRICAL CHARACTERISTICS

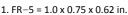
(T_A = 25°C unless otherwise noted)

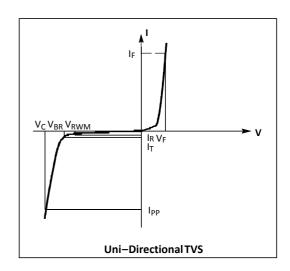
Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ IPP
V _{RWM}	Working Peak Reverse Voltage
lR	Maximum Reverse Leakage Current @ VRwм
V _{BR}	Breakdown Voltage @ I _T
ΙΤ	Test Current
lF	Forward Current
VF	Forward Voltage @ IF
P _{pk}	Peak Power Dissipation
С	Capacitance @ V _R = 0 and f = 1.0 MHz

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Contact Air		±10 ±15	kV
Total Power Dissipation on FR-5 Board (Note 1) @ T _A = 25°C	P _D	150	mW
Storage Temperature Range	T _{stg}	-55 to +150	°C
Junction Temperature Range	TJ	-55 to +125	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

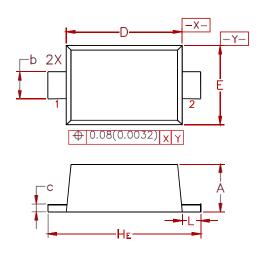






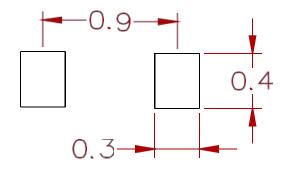


PACKAGE MECHANICAL DATA



		Millimeters		Inches			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.36	0.40	0.43	0.014	0.016	0.017	
b	0.15	0.20	0.25	0.006	0.008	0.010	
С	0.07	0.12	0.17	0.003	0.005	0.007	
D	0.75	0.80	0.85	0.030	0.031	0.033	
E	0.55	0.60	0.65	0.022	0.024	0.026	
HE	0.95	1.00	1.05	0.037	0.039	0.041	
L	0.05	0.10	0.15	0.002	0.004	0.006	

Suggested Pad Layout



Dimensions: Millimeters

REEL SPECIFICATION

P/N	PKG	QTY
ESD9X5.0ST5G-MS	SOD-923	8000



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